# S-8215A Series

# BATTERY PROTECTION IC FOR 3-SERIAL TO 5-SERIAL CELL PACK (SECONDARY PROTECTION)

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SII

Rev.2.3 00

The S-8215A Series is used for secondary protection of lithium-ion rechargeable batteries, and incorporates high-accuracy voltage detection circuits and delay circuits.

Short-circuiting between cells makes it possible for serial connection of three cells to five cells.

# Features

· High-accuracy voltage detection circuit for each cell Overcharge detection voltage n (n = 1 to 5) 3.60 V to 4.70 V (50 mV step) Accuracy  $\pm 25 \text{ mV}$  (Ta =  $+25^{\circ}$ C) Accuracy  $\pm 30 \text{ mV}$  (Ta =  $-5^{\circ}\text{C}$  to  $+55^{\circ}\text{C}$ ) Overcharge hysteresis voltage n (n = 1 to 5) 0.0 mV to -550 mV (50 mV step) -300 mV to -550 mV Accuracy ±20% -100 mV to -250 mV Accuracy ±50 mV 0.0 mV to -50 mV Accuracy ±25 mV Delay times for overcharge detection can be set by an internal circuit only (External capacitors are unnecessary). • Output form is selectable: CMOS output, Nch open-drain output, Pch open-drain output • Output logic is selectable: Active "H", active "L" • High-withstand voltage device: Absolute maximum rating 28 V Wide operation voltage range: 3.6 V to 26 V • Wide operation temperature range: Ta =  $-40^{\circ}$ C to  $+85^{\circ}$ C Low current consumption At  $V_{CUn} - 1.0$  V for each cell: 3.0  $\mu$ A max. (Ta = +25°C) 1.7  $\mu$ A max. (Ta = +25°C) At 2.3 V for each cell: • Lead-free (Sn 100%), halogen-free

# Application

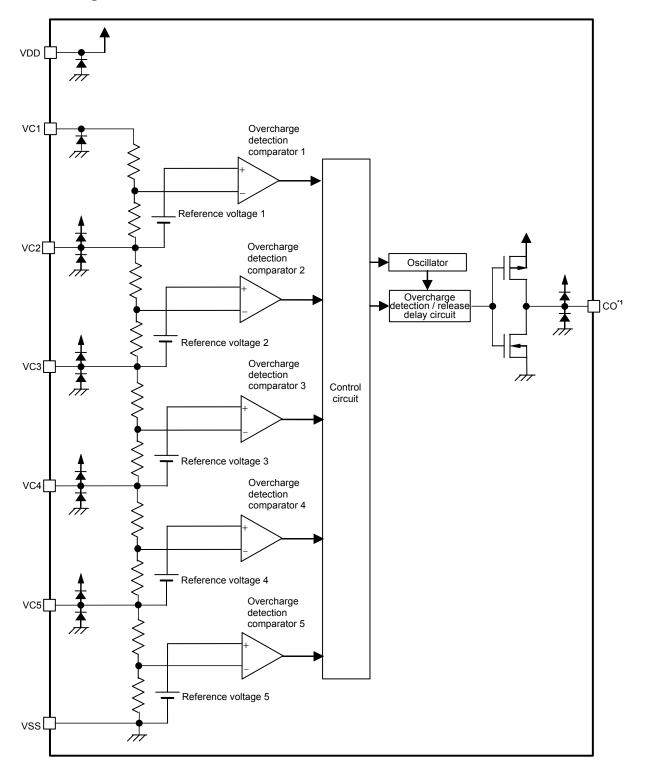
• Lithium-ion rechargeable battery pack (for secondary protection)

# Packages

- TMSOP-8
- SNT-8A

# BATTERY PROTECTION IC FOR 3-SERIAL TO 5-SERIAL CELL PACK (SECONDARY PROTECTION) S-8215A Series Rev.2.3\_00

Block Diagram



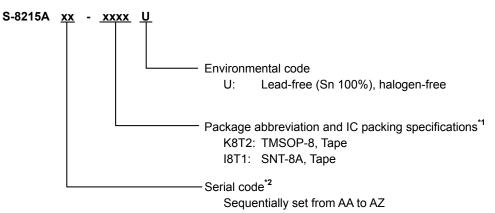
\*1. The CO pin is connected only to Nch transistor in the case of Nch open-drain output. The CO pin is connected only to Pch transistor in the case of Pch open-drain output.

**Remark** The diodes in the figure are parasitic diodes.

### Figure 1

## Product Name Structure

1. Product name



\*1. Refer to the tape drawing.

\*2. Refer to "3. Product name list".

## 2. Packages

Table 1 Package Drawing Codes

| Package Name | Dimension    | Таре         | Reel         | Land         |
|--------------|--------------|--------------|--------------|--------------|
| TMSOP-8      | FM008-A-P-SD | FM008-A-C-SD | FM008-A-R-SD | _            |
| SNT-8A       | PH008-A-P-SD | PH008-A-C-SD | PH008-A-R-SD | PH008-A-L-SD |

# BATTERY PROTECTION IC FOR 3-SERIAL TO 5-SERIAL CELL PACK (SECONDARY PROTECTION) S-8215A Series Rev.2.3\_00

Table 2

## 3. Product name list

## 3.1 TMSOP-8

| Product Name    | Overcharge<br>Detection<br>Voltage<br>[Vcu] | Overcharge<br>Hysteresis<br>Voltage<br>[V <sub>HC</sub> ] | Overcharge<br>Detection<br>Delay Time<br>[t <sub>cu</sub> ] | Output Form           | Output Logic |
|-----------------|---|---|---|-----------------------|--------------|
| S-8215AAA-K8T2U | 4.300 V                                     | –0.30 V   | 4.0 s   | CMOS output           | Active "H"   |
| S-8215AAB-K8T2U | 4.275 V                                     | –0.05 V   | 2.0 s   | Nch open-drain output | Active "L"   |
| S-8215AAC-K8T2U | 4.150 V                                     | –0.25 V   | 1.0 s   | CMOS output           | Active "H"   |
| S-8215AAD-K8T2U | 4.350 V                                     | –0.25 V   | 2.0 s   | CMOS output           | Active "H"   |
| S-8215AAE-K8T2U | 4.325 V                                     | –0.05 V   | 1.0 s   | Nch open-drain output | Active "L"   |
| S-8215AAF-K8T2U | 4.220 V                                     | –0.10 V   | 1.0 s   | CMOS output           | Active "H"   |
| S-8215AAH-K8T2U | 4.325 V                                     | –0.30 V   | 1.0 s   | Nch open-drain output | Active "L"   |
| S-8215AAI-K8T2U | 4.250 V                                     | –0.25 V   | 1.0 s   | CMOS output           | Active "H"   |
| S-8215AAJ-K8T2U | 4.400 V                                     | –0.10 V   | 2.0 s   | CMOS output           | Active "H"   |
| S-8215AAK-K8T2U | 4.150 V                                     | –0.05 V   | 2.0 s   | Nch open-drain output | Active "L"   |
| S-8215AAL-K8T2U | 4.150 V                                     | –0.50 V   | 2.0 s   | Nch open-drain output | Active "L"   |
| S-8215AAM-K8T2U | 4.150 V                                     | –0.05 V   | 2.0 s   | CMOS output           | Active "L"   |
| S-8215AAN-K8T2U | 4.150 V                                     | –0.50 V   | 2.0 s   | CMOS output           | Active "L"   |
| S-8215AAO-K8T2U | 4.350 V                                     | –0.25 V   | 4.0 s   | CMOS output           | Active "H"   |
| S-8215AAP-K8T2U | 4.275 V                                     | –0.50 V   | 1.0 s   | CMOS output           | Active "H"   |
| S-8215AAQ-K8T2U | 4.275 V                                     | –0.05 V   | 1.0 s   | CMOS output           | Active "H"   |

**Remark** Please contact our sales office for the products with detection voltage value other than those specified above.

#### 3.2 SNT-8A

Table 3

| Product Name    | Overcharge<br>Detection<br>Voltage<br>[Vcu] | Overcharge<br>Hysteresis<br>Voltage<br>[V <sub>HC</sub> ] | Overcharge<br>Detection<br>Delay Time<br>[t <sub>cu</sub> ] | Output Form | Output Logic |
|-----------------|---|---|---|-------------|--------------|
| S-8215AAA-I8T1U | 4.300 V                                     | –0.30 V   | 4.0 s   | CMOS output | Active "H"   |
| S-8215AAG-I8T1U | 4.220 V                                     | –0.05 V   | 1.0 s   | CMOS output | Active "H"   |

**Remark** Please contact our sales office for the products with detection voltage value other than those specified above.

# Pin Configurations

# 1. TMSOP-8

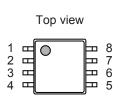


Figure 2

Table 4 Symbol Pin No. Description VDD 1 Input pin for positive power supply 2 VC1 Positive voltage connection pin of battery 1 Negative voltage connection pin of battery 1 VC2 3 Positive voltage connection pin of battery 2 Negative voltage connection pin of battery 2 VC3 4 Positive voltage connection pin of battery 3 Negative voltage connection pin of battery 3 5 VC4 Positive voltage connection pin of battery 4 Negative voltage connection pin of battery 4 6 VC5 Positive voltage connection pin of battery 5 Input pin for negative power supply 7 VSS Negative voltage connection pin of battery 5 8 со FET gate connection pin for charge control

#### 2. SNT-8A

Top view 1 2 3 4 1 6 5

Figure 3

|         |        | Table 5  |
|---------|--------|--|
| Pin No. | Symbol | Description  |
| 1       | VDD    | Input pin for positive power supply  |
| 2       | VC1    | Positive voltage connection pin of battery 1   |
| 3       | VC2    | Negative voltage connection pin of battery 1<br>Positive voltage connection pin of battery 2 |
| 4       | VC3    | Negative voltage connection pin of battery 2<br>Positive voltage connection pin of battery 3 |
| 5       | VC4    | Negative voltage connection pin of battery 3<br>Positive voltage connection pin of battery 4 |
| 6       | VC5    | Negative voltage connection pin of battery 4<br>Positive voltage connection pin of battery 5 |
| 7       | VSS    | Input pin for negative power supply<br>Negative voltage connection pin of battery 5          |
| 8       | CO     | FET gate connection pin for charge control   |

# Absolute Maximum Ratings

Table 6 (Ta = +25°C unless otherwise specified) Item Applied Pin Absolute Maximum Rating Unit Symbol Input voltage between VDD pin and VSS pin  $V_{\text{SS}}-0.3$  to  $V_{\text{SS}}+28$ V VDS VDD  $V_{\text{SS}} - 0.3$  to  $V_{\text{DD}} + 0.3$ VC1, VC2, VC3, VC4, VC5 V Input pin voltage VIN CMOS output product  $V_{SS} - 0.3$  to  $V_{DD} + 0.3$ V CO pin СО Nch open-drain output product V<sub>CO</sub>  $V_{\text{SS}}-0.3$  to  $V_{\text{SS}}+28$ V output voltage Pch open-drain output product  $V_{\text{DD}}-28$  to  $V_{\text{DD}}+0.3$ V 650<sup>\*1</sup> Power TMSOP-8 mW  $\mathbf{P}_{\mathsf{D}}$ \_ 450<sup>\*1</sup> dissipation SNT-8A mW Operation ambient temperature Topr -40 to +85 °C \_ Storage temperature -40 to +125 °C T<sub>stg</sub> \_

\*1. When mounted on board

[Mounted board]

(1) Board size:  $114.3 \text{ mm} \times 76.2 \text{ mm} \times t1.6 \text{ mm}$ 

(2) Name: JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

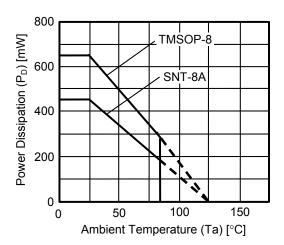


Figure 4 Power Dissipation of Package (When Mounted on Board)

# Electrical Characteristics

Table 7

|  |                   | Table 7  | (Ta =                      | = +25°(         | C unless oth               | nerwise s | pecified)       |
|--|-------------------|--|----------------------------|-----------------|----------------------------|-----------|-----------------|
| Item   | Symbol            | Condition  | Min.                       | Тур.            | Max.                       | Unit      | Test<br>Circuit |
| Detection Voltage                                      |                   |  |                            |                 |                            |           |                 |
| Overcharge detection                                   | V                 | _  | V <sub>CU</sub><br>- 0.025 | $V_{\text{CU}}$ | V <sub>CU</sub><br>+ 0.025 | V         | 1               |
| voltage n (n = 1, 2, 3, 4, 5)                          | V <sub>CUn</sub>  | Ta = –5°C to +55°C <sup>*1</sup>                 | V <sub>CU</sub><br>- 0.030 | V <sub>CU</sub> | V <sub>CU</sub><br>+ 0.030 | V         | 1               |
|  |                   | –550 mV ≤ V <sub>HC</sub> ≤ –300 mV              | $V_{HC} \times 0.8$        | $V_{\text{HC}}$ | $V_{HC} \times 1.2$        | V         | 1               |
| Overcharge hysteresis<br>voltage n (n = 1, 2, 3, 4, 5) | V <sub>HCn</sub>  | –250 mV ≤ V <sub>HC</sub> ≤ –100 mV              | V <sub>HC</sub><br>- 0.050 | $V_{\text{HC}}$ | V <sub>HC</sub><br>+ 0.050 | V         | 1               |
| voltage $\Pi$ ( $\Pi = 1, 2, 3, 4, 5$ )                |                   | V <sub>HC</sub> = -50 mV, 0 mV                   | V <sub>HC</sub><br>- 0.025 | $V_{\text{HC}}$ | V <sub>HC</sub><br>+ 0.025 | V         | 1               |
| Input Voltage  |                   |  | · · · · · · ·              |                 |                            |           | <u>.</u>        |
| Operation voltage between<br>VDD pin and VSS pin       | VDSOP             | _  | 3.6                        | _               | 26                         | V         | -               |
| Input Current  |                   |  |                            |                 |                            |           |                 |
| Current consumption during operation                   | I <sub>OPE</sub>  | V1 = V2 = V3 = V4 = V5 = V <sub>CU</sub> – 1.0 V | -                          | 1.6             | 3.0                        | μA        | 3               |
| Current consumption during<br>overdischarge            | I <sub>OPED</sub> | V1 = V2 = V3 = V4 = V5 = 2.3 V                   | -                          | 0.8             | 1.7                        | μA        | 3               |
| VC1 pin current  | I <sub>VC1</sub>  | V1 = V2 = V3 = V4 = V5 = V <sub>CU</sub> - 1.0 V | -                          | 0.2             | 0.4                        | μΑ        | 4               |
| VCn pin current<br>(n = 2, 3, 4, 5)                    | I <sub>VCn</sub>  | V1 = V2 = V3 = V4 = V5 = V <sub>CU</sub> – 1.0 V | -0.3                       | 0               | 0.3                        | μA        | 4               |
| <b>Output Current (CMOS Out</b>                        | put Prod          | uct)   |                            |                 |                            |           |                 |
| CO pin sink current                                    | I <sub>COL</sub>  | _  | 0.4                        | _               | -                          | mA        | 5               |
| CO pin source current                                  | Ісон              | _  | 20                         | _               | -                          | μA        | 5               |
| Output Current (Nch Open-                              | drain Ou          | tput Product)                                    |                            |                 |                            |           |                 |
| CO pin sink current                                    | ICOL              | _  | 0.4                        | _               | -                          | mA        | 5               |
| CO pin leakage current "L"                             | ICOLL             | _  | -                          | _               | 0.1                        | μA        | 5               |
| Output Current (Pch Open-                              | drain Ou          | tput Product)                                    |                            |                 |                            |           |                 |
| CO pin source current                                  | I <sub>COH</sub>  |  | 20                         | _               | _                          | μA        | 5               |
| CO pin leakage current "H"                             | ICOLH             | _  | _                          | -               | 0.1                        | μA        | 5               |
| Delay Time   |                   |  |                            |                 |                            |           |                 |
| Overcharge detection delay time                        | t <sub>CU</sub>   | _  | $t_{\text{CU}} \times 0.8$ | t <sub>cu</sub> | $t_{\text{CU}} \times 1.2$ | s         | 1               |
| Overcharge timer reset delay time                      | t <sub>TR</sub>   | _  | 6                          | 12              | 20                         | ms        | 1               |
| Transition time to test mode                           | t <sub>TST</sub>  | _  | _                          | _               | 80                         | ms        | 2               |

\*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

# Test Circuits

1. Overcharge detection voltage, overcharge hysteresis voltage (Test circuit 1)

#### 1. 1 Overcharge detection voltage n (Vcun)

Set V1 = V2 = V3 = V4 = V5 =  $V_{CU} - 0.05$  V. The overcharge detection voltage 1 ( $V_{CU1}$ ) is the V1 voltage when the CO pin's output changes after the voltage of V1 has been gradually increased.

Overcharge detection voltage ( $V_{CUn}$ ) (n = 2 to 5) can be determined in the same way as when n = 1.

#### 1. 2 Overcharge hysteresis voltage n (V<sub>HCn</sub>)

Set V1 =  $V_{CU}$  + 0.05 V, V2 = V3 = V4 = V5 = 2.5 V. The overcharge hysteresis voltage 1 (V<sub>HC1</sub>) is the difference between V1 voltage and V<sub>CU1</sub> when the CO pin's output changes after the V1 voltage has been gradually decreased. Overcharge hysteresis voltage (V<sub>HCn</sub>) (n = 2 to 5) can be determined in the same way as when n = 1.

# 2. Output current

## (Test circuit 5)

#### 2.1 Output current of CMOS output product

Set SW1 and SW2 to OFF.

#### 2.1.1 Active "H"

- (1) CO pin source current (I<sub>COH</sub>) Set SW1 to ON after setting V1 = 5.5 V, V2 to V5 = 3.0 V, V6 = 0.5 V. I1 is the CO pin source current (I<sub>COH</sub>) at that time.
- (2) CO pin sink current (I<sub>COL</sub>) Set SW2 to ON after setting V1 to V5 = 3.5 V, V7 = 0.5 V. I2 is the CO pin sink current (I<sub>COL</sub>) at that time.

#### 2. 1. 2 Active "L"

- (1) CO pin source current (I<sub>COH</sub>) Set SW1 to ON after setting V1 to V5 = 3.5 V, V6 = 0.5 V. I1 is the CO pin source current (I<sub>COH</sub>) at that time.
- (2) CO pin sink current (I<sub>COL</sub>) Set SW2 to ON after setting V1 = 5.5 V, V2 to V5 = 3.0 V, V7 = 0.5 V. I2 is the CO pin sink current (I<sub>COL</sub>) at that time.

#### 2. 2 Output current of Nch open-drain output product

Set SW1 and SW2 to OFF.

#### 2. 2. 1 Active "H"

(1) CO pin leakage current "L" (I<sub>COLL</sub>)

Set SW2 to ON after setting V1 = 5.5 V, V2 to V5 = 3.0 V, V7 = 17.5 V. I2 is the CO pin leakage current "L" ( $I_{COLL}$ ) at that time.

- (2) CO pin sink current ( $I_{COL}$ ) Set V1 to V5 = 3.5 V, V7 = 0.5 V. I2 is the CO pin sink current ( $I_{COL}$ ) at that time.
- 2. 2. 2 Active "L"
  - (1) CO pin leakage current "L" (I<sub>COLL</sub>)

Set SW2 to ON after setting V1 to V5 = 3.5 V, V7 = 17.5 V. I2 is the CO pin leakage current "L" (I<sub>COLL</sub>) at that time.

(2) CO pin sink current (I<sub>COL</sub>)

Set V1 = 5.5 V, V2 to V5 = 3.0 V, V7 = 0.5 V. I2 is the CO pin sink current ( $I_{COL}$ ) at that time.

#### 2. 3 Output current of Pch open-drain output product

Set SW1 and SW2 to OFF.

#### 2. 3. 1 Active "H"

(1) CO pin source current (I<sub>COH</sub>)

Set SW1 to ON after setting V1 = 5.5 V, V2 to V5 = 3.0 V, V6 = 0.5 V. I1 is the CO pin source current ( $I_{COH}$ ) at that time.

- (2) CO pin leakage current "H" (I<sub>COLH</sub>) Set V1 to V5 = 3.5 V, V6 = 17.5 V. I1 is the CO pin leakage current "H" (I<sub>COLH</sub>) at that time.
- 2. 3. 2 Active "L"
  - (1) CO pin source current ( $I_{COH}$ ) Set SW1 to ON after setting V1 to V5 = 3.5 V, V6 = 0.5 V. I1 is the CO pin source current ( $I_{COH}$ ) at that time.
  - (2) CO pin leakage current "H" (I<sub>COLH</sub>) Set V1 = 5.5 V, V2 to V5 = 3.0 V, V6 = 17.5 V. I1 is the CO pin leakage current "H" (I<sub>COLH</sub>) at that time.

# 3. Overcharge detection delay time (t<sub>CU</sub>) (Test circuit 1)

Increase V1 up to 5.0 V after setting V1 = V2 = V3 = V4 = V5 = 3.5 V. The overcharge detection delay time ( $t_{CU}$ ) is the time period until the CO pin output changes.

#### Overcharge timer reset delay time (t<sub>TR</sub>) (Test circuit 1)

Increase V1 up to 5.0 V (first rise), and decrease V1 down to 3.5 V within  $t_{CU}$  after setting V1 = V2 = V3 = V4 = V5 = 3.5 V. After that, increase V1 up to 5.0 V again (second rise), and detect the time period till the CO pin output changes. When the period from when V1 has fallen to the second rise is short, CO pin output changes after  $t_{CU}$  has elapsed since the first rise. If the period is gradually made longer, CO pin output changes after  $t_{CU}$  has elapsed since the second rise. The overcharge timer reset delay time ( $t_{TR}$ ) is the period from V1 fall till the second rise at that time.

# 5. Transition time to test mode (t<sub>TST</sub>) (Test circuit 2)

Increase V6 up to 5.0 V, and decrease V6 again to 0 V after setting V1 = V2 = V3 = V4 = V5 = 3.5 V, and V6 = 0 V. When the period from when V6 was raised to when it has fallen is short, if an overcharge detection operation is performed subsequently, the delay time is  $t_{CU}$ . However, when the period from when V6 is raised to when it has fallen is gradually made longer, the delay time during the subsequent overcharge detection operation is shorter than  $t_{CU}$ . The transition time to test mode ( $t_{TST}$ ) is the period from when V6 was raised to when it has fallen at that time.

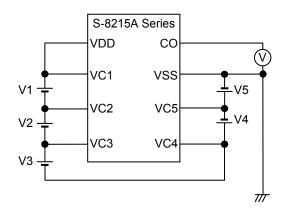
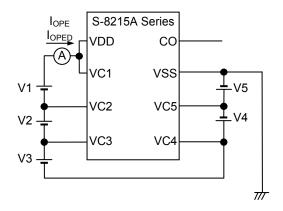


Figure 5 Test Circuit 1





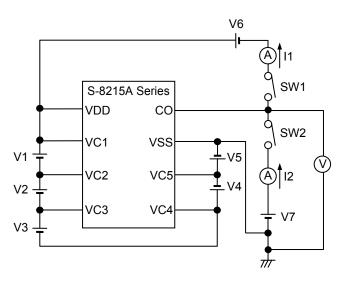


Figure 9 Test Circuit 5

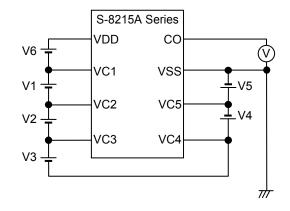


Figure 6 Test Circuit 2

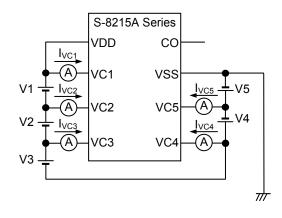


Figure 8 Test Circuit 4

## Operation

**Remark** Refer to "
Battery Protection IC Connection Examples".

#### 1. Normal status

If the voltage of each of the batteries is lower than "the overcharge detection voltage n ( $V_{CUn}$ ) + the overcharge hysteresis voltage n ( $V_{HCn}$ )", the CO pin output changes to "L" (Active "H") or "H" (Active L"). This is called normal status.

#### 2. Overcharge status

When the voltage of one of the batteries exceeds  $V_{CUn}$  during charging under normal conditions and the status is retained for the overcharge detection delay time ( $t_{CU}$ ) or longer, the CO pin output changes. This is called overcharge status. Connecting FET to the CO pin provides charge control and a second protection.

If the voltage of each of the batteries is lower than  $V_{CUn} + V_{HCn}$  and the status is retained for 2.0 ms typ. or longer, the S-8215A Series changes to normal status.

#### 3. Overcharge timer reset

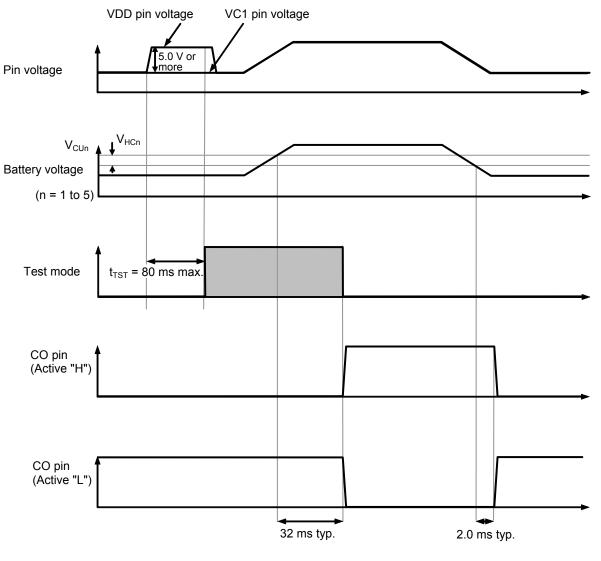
When an overcharge release noise that forces the voltage of one of the batteries temporarily below  $V_{CUn}$  is input during  $t_{CU}$  from when  $V_{CUn}$  is exceeded to when charging is stopped,  $t_{CU}$  is continuously counted if the time the overcharge release noise persists is shorter than the overcharge timer reset delay time ( $t_{TR}$ ). Under the same conditions, if the time the overcharge release noise persists is  $t_{TR}$  or longer, counting of  $t_{CU}$  is reset once. After that, when  $V_{CUn}$  has been exceeded, counting  $t_{CU}$  resumes.

## 4. Test mode

The overcharge detection delay time  $(t_{CU})$  can be shortened by entering the test mode.

The test mode can be set by retaining the VDD pin voltage 5.0 V or more higher than the VC1 pin voltage for the transition time to test mode ( $t_{TST}$ ) or longer. The status is retained by the internal latch and the test mode is retained even if the VDD pin voltage is decreased to the same voltage as that of the VC1 pin voltage.

After that, the latch for retaining the test mode is reset and the S-8215A Series exits from test mode under the overcharge status.





- Caution 1. When the VDD pin voltage is decreased to lower than the UVLO voltage of 2 V typ., the S-8215A Series exits from test mode.
  - 2. Set the test mode when no batteries are overcharged.
  - 3. The overcharge timer reset delay time ( $t_{TR}$ ) is not shortened in the test mode.

# ■ Timing Charts

# 1. Overcharge detection operation

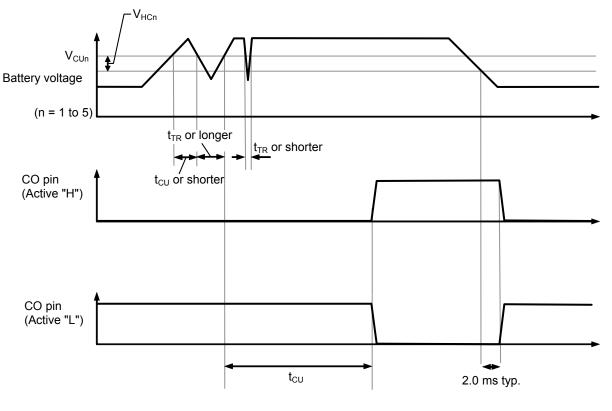
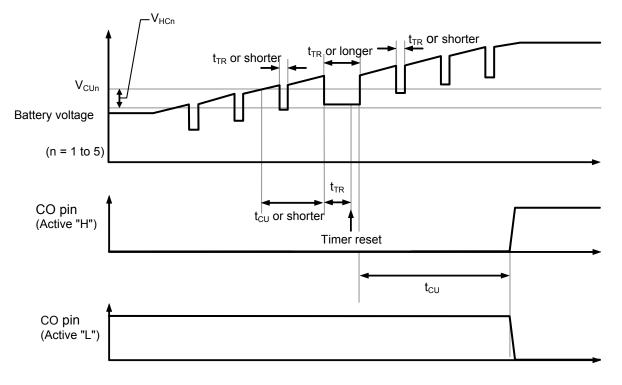


Figure 11



## 2. Overcharge timer reset operation



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# Battery Protection IC Connection Examples

1. 5-serial cell

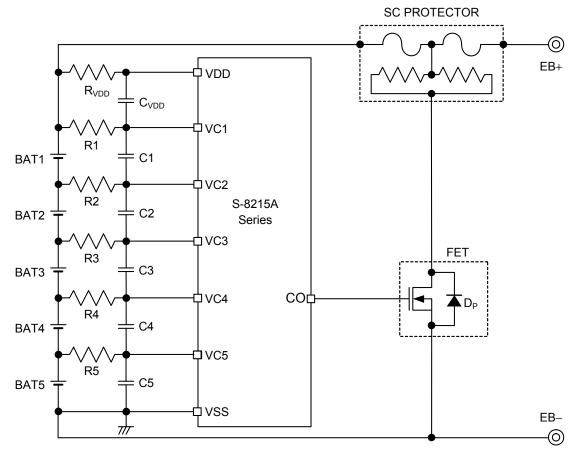


Figure 13

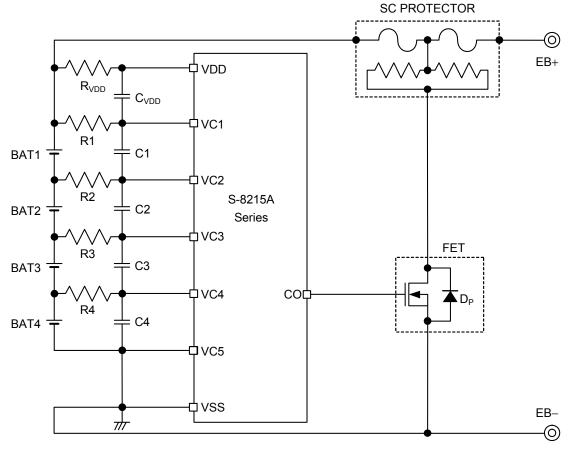
Table 8 Constants for External Components

| No. | Part                       | Min. | Тур. | Max. | Unit |
|-----|----------------------------|------|------|------|------|
| 1   | R1 to R5                   | 0.5  | 1    | 10   | kΩ   |
| 2   | C1 to C5, C <sub>VDD</sub> | 0.01 | 0.1  | 1    | μF   |
| 3   | R <sub>VDD</sub>           | 50   | 100  | 500  | Ω    |

Caution 1. The above constants are subject to change without prior notice.

- It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.
- 3. R1 to R5 should be the same constant. C1 to C5 and  $C_{VDD}$  should be the same constant.
- 4. Set  $R_{VDD}$ , C1 to C5, and  $C_{VDD}$  so that the condition ( $R_{VDD}$ ) × (C1 to C5,  $C_{VDD}$ ) ≥ 5 × 10<sup>-6</sup> is satisfied.
- 5. Set R1 to R5, C1 to C5, and  $C_{VDD}$  so that the condition (R1 to R5) × (C1 to C5,  $C_{VDD}$ )  $\ge$  1 × 10<sup>-4</sup> is satisfied.
- 6. Since the CO pin may become detection status transiently when the battery is being connected, connect the positive terminal of BAT1 last in order to prevent the three terminal protection fuse from cutoff.

## 2. 4-serial cell





**Table 9 Constants for External Components** 

| No. | Part                       | Min. | Тур. | Max. | Unit |
|-----|----------------------------|------|------|------|------|
| 1   | R1 to R4                   | 0.5  | 1    | 10   | kΩ   |
| 2   | C1 to C4, C <sub>VDD</sub> | 0.01 | 0.1  | 1    | μF   |
| 3   | R <sub>VDD</sub>           | 50   | 100  | 500  | Ω    |

Caution 1. The above constants are subject to change without prior notice.

- It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.
- 3. R1 to R4 should be the same constant. C1 to C4 and C<sub>VDD</sub> should be the same constant.
- 4. Set  $R_{VDD}$ , C1 to C4, and  $C_{VDD}$  so that the condition ( $R_{VDD}$ ) × (C1 to C4,  $C_{VDD}$ ) ≥ 5 × 10<sup>-6</sup> is satisfied.
- 5. Set R1 to R4, C1 to C4, and  $C_{VDD}$  so that the condition (R1 to R4) × (C1 to C4,  $C_{VDD}$ ) ≥ 1 × 10<sup>-4</sup> is satisfied.
- 6. Since the CO pin may become detection status transiently when the battery is being connected, connect the positive terminal of BAT1 last in order to prevent the three terminal protection fuse from cutoff.

## 3. 3-serial cell

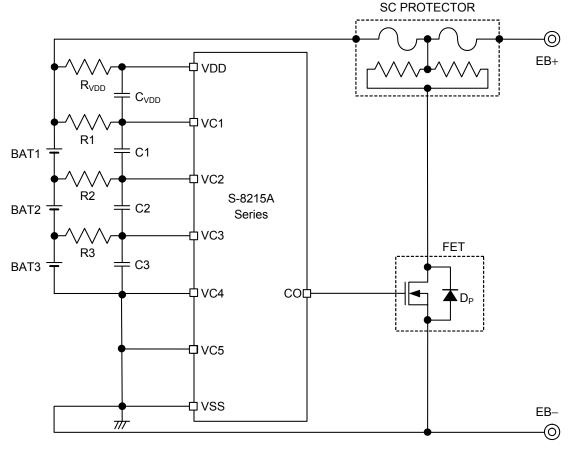




Table 10 Constants for External Components

| No. | Part                       | Min. | Тур. | Max. | Unit |
|-----|----------------------------|------|------|------|------|
| 1   | R1 to R3                   | 0.5  | 1    | 10   | kΩ   |
| 2   | C1 to C3, C <sub>VDD</sub> | 0.01 | 0.1  | 1    | μF   |
| 3   | R <sub>VDD</sub>           | 50   | 100  | 500  | Ω    |

Caution 1. The above constants are subject to change without prior notice.

- It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.
- 3. R1 to R3 should be the same constant. C1 to C3 and C<sub>VDD</sub> should be the same constant.
- 4. Set  $R_{VDD}$ , C1 to C3, and  $C_{VDD}$  so that the condition ( $R_{VDD}$ ) × (C1 to C3,  $C_{VDD}$ ) ≥ 5 × 10<sup>-6</sup> is satisfied.
- 5. Set R1 to R3, C1 to C3, and  $C_{VDD}$  so that the condition (R1 to R3) × (C1 to C3,  $C_{VDD}$ ) ≥ 1 × 10<sup>-4</sup> is satisfied.
- 6. Since the CO pin may become detection status transiently when the battery is being connected, connect the positive terminal of BAT1 last in order to prevent the three terminal protection fuse from cutoff.

#### [For SC PROTECTOR, contact]

Device Sales Dept., Advanced Process Device Division, Dexerials Corporation Gate City Osaki East Tower 8F, 1-11-2 Osaki, Shinagawa-ku, Tokyo, 141-0032 Japan TEL +81-3-5435-3946 Contact Us: http://www.dexerials.jp/en/

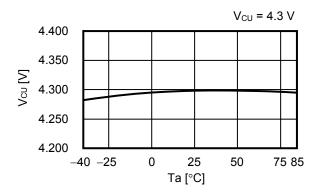
# Precautions

- Do not connect batteries charged with V<sub>CUn</sub> + V<sub>HCn</sub> or higher. If the connected batteries include a battery charged with V<sub>CUn</sub> + V<sub>HCn</sub> or higher, the S-8215A series may become overcharge status after all pins are connected.
- In some application circuits, even if an overcharged battery is not included, the order of connecting batteries may be restricted to prevent transient output of CO detection pulses when the batteries are connected. Perform thorough evaluation with the actual application circuit.
- Before the battery connection, short-circuit the battery side pins R<sub>VDD</sub> and R1, shown in the figure in "■ Battery Protection IC Connection Examples".
- The application conditions for the input voltage, output voltage, and load current should not exceed the package power dissipation.
- Do not apply to this IC an electrostatic discharge that exceeds the performance ratings of the built-in electrostatic protection circuit.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement of patents owned by a third party by products including this IC.

# Characteristics (Typical Data)

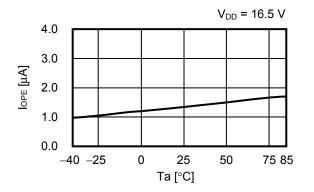
## 1. Detection voltage

1.1  $V_{CU}$  vs. Ta

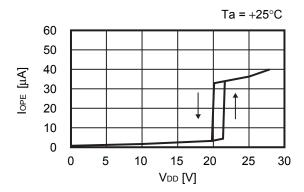


## 2. Current consumption

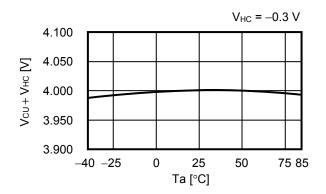
2.1 IOPE vs. Ta



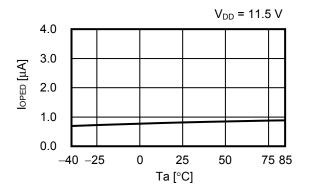
2. 3 IOPE VS. VDD



1. 2 V<sub>CU</sub> + V<sub>HC</sub> vs. Ta



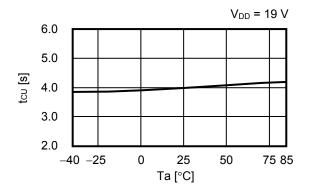




#### BATTERY PROTECTION IC FOR 3-SERIAL TO 5-SERIAL CELL PACK (SECONDARY PROTECTION) S-8215A Series Rev.2.3\_00

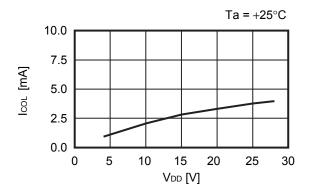
## 3. Delay time

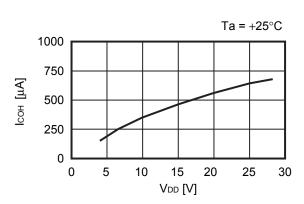
3.1  $t_{CU}$  vs. Ta



# 4. Output current

4.1 ICOL VS. VDD

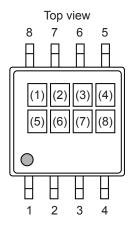




#### 4. 2 ICOH VS. VDD

# Marking Specifications

# 1. TMSOP-8

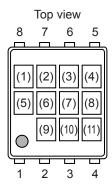


(1): (2) to (4): (5): (6) to (8): Blank Product code (Refer to Product name vs. Product code) Blank Lot number

#### Product name vs. Product code

| Product Name    | Pro | oduct Co | de  |
|-----------------|-----|----------|-----|
| Product Name    | (2) | (3)      | (4) |
| S-8215AAA-K8T2U | V   | 6        | А   |
| S-8215AAB-K8T2U | V   | 6        | В   |
| S-8215AAC-K8T2U | V   | 6        | С   |
| S-8215AAD-K8T2U | V   | 6        | D   |
| S-8215AAE-K8T2U | V   | 6        | Е   |
| S-8215AAF-K8T2U | V   | 6        | F   |
| S-8215AAH-K8T2U | V   | 6        | Н   |
| S-8215AAI-K8T2U | V   | 6        | I   |
| S-8215AAJ-K8T2U | V   | 6        | J   |
| S-8215AAK-K8T2U | V   | 6        | К   |
| S-8215AAL-K8T2U | V   | 6        | L   |
| S-8215AAM-K8T2U | V   | 6        | М   |
| S-8215AAN-K8T2U | V   | 6        | Ν   |
| S-8215AAO-K8T2U | V   | 6        | 0   |
| S-8215AAP-K8T2U | V   | 6        | Р   |
| S-8215AAQ-K8T2U | V   | 6        | Q   |

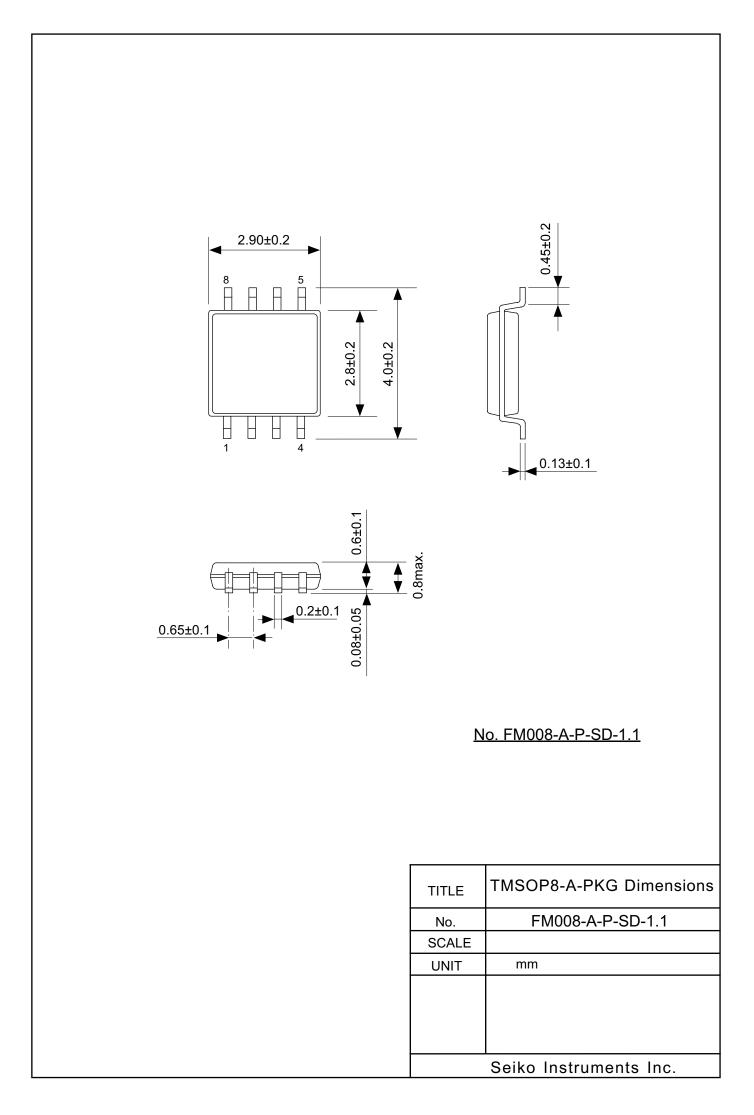
## 2. SNT-8A

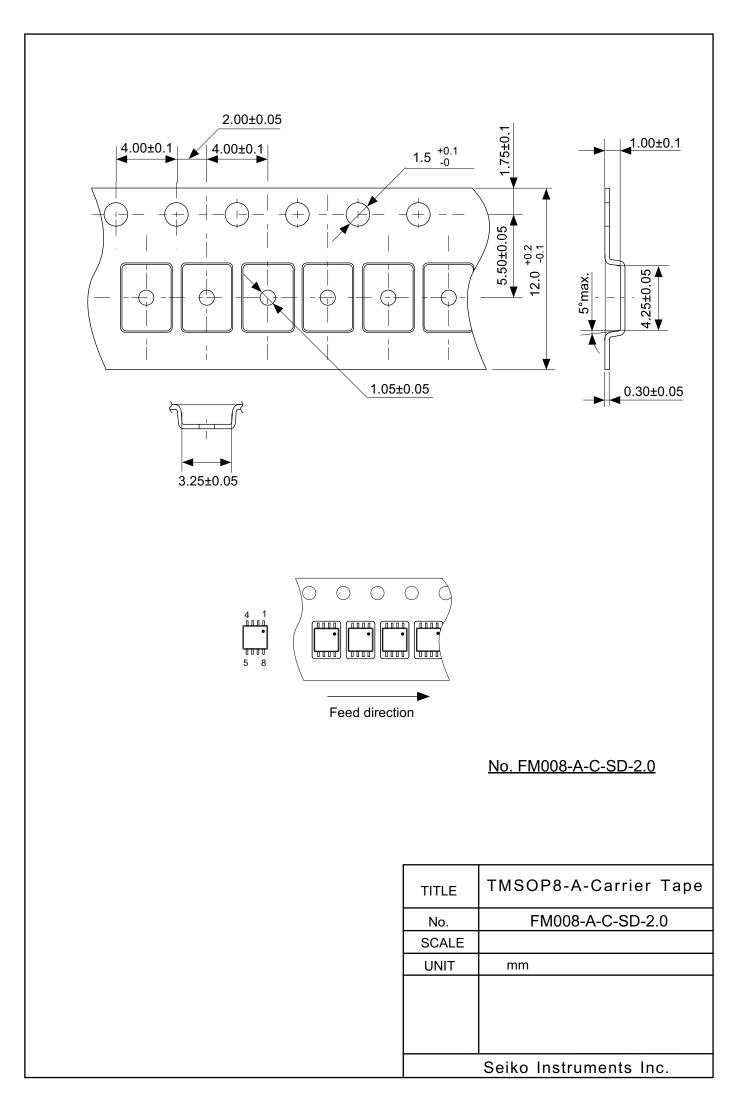


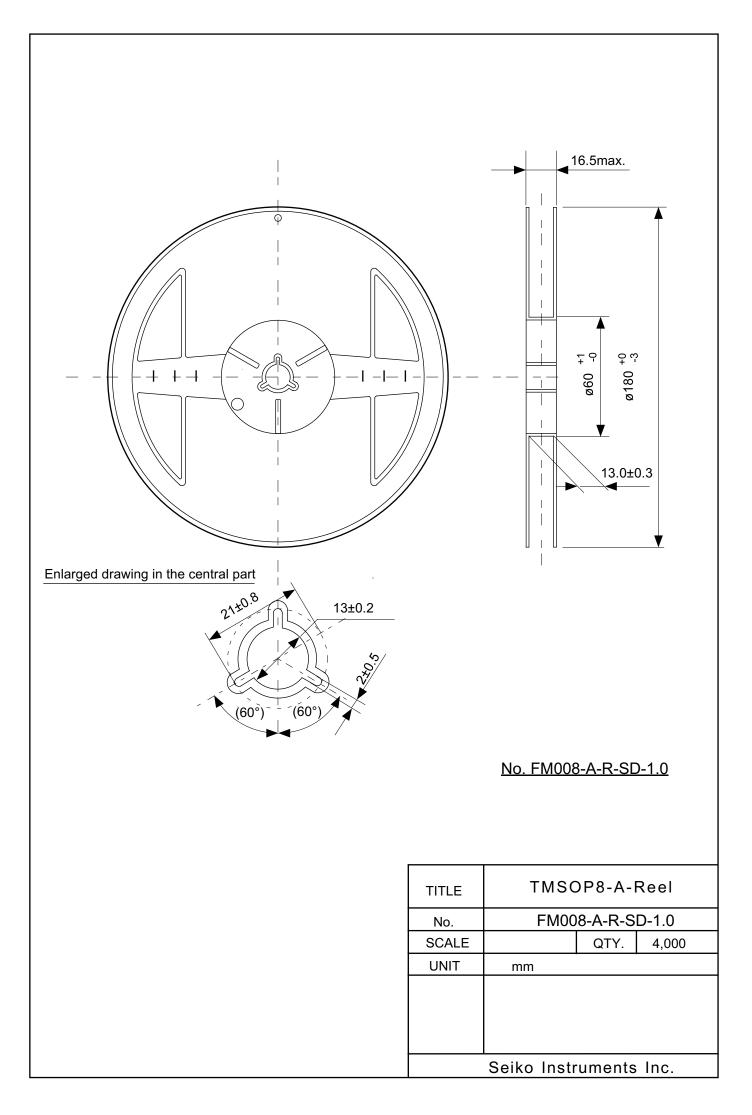
| (1):         | Blank   |
|--------------|---|
| (2) to (4):  | Product code (Refer to <b>Product name vs. Product code</b> ) |
| (5), (6):    | Blank   |
| (7) to (11): | Lot number  |

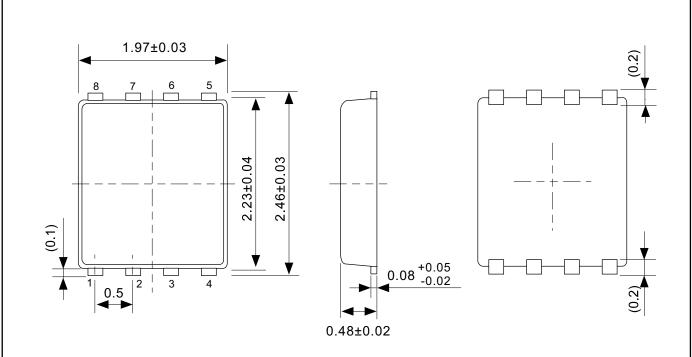
#### Product name vs. Product code

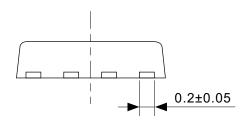
| Draduct Name    | Product Code |     |     |  |
|-----------------|--------------|-----|-----|--|
| Product Name    | (2)          | (3) | (4) |  |
| S-8215AAA-I8T1U | V            | 6   | А   |  |
| S-8215AAG-I8T1U | V            | 6   | G   |  |





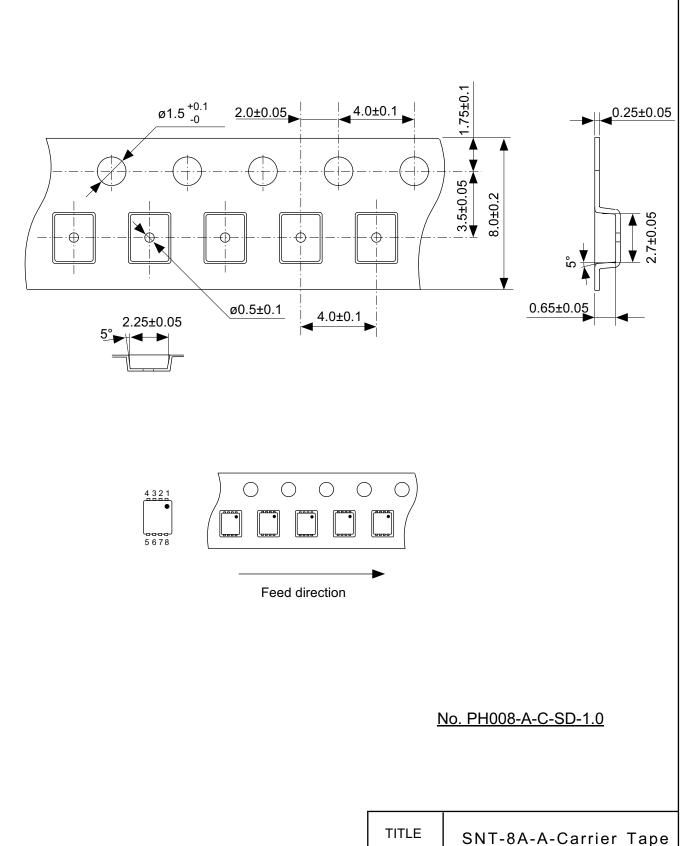




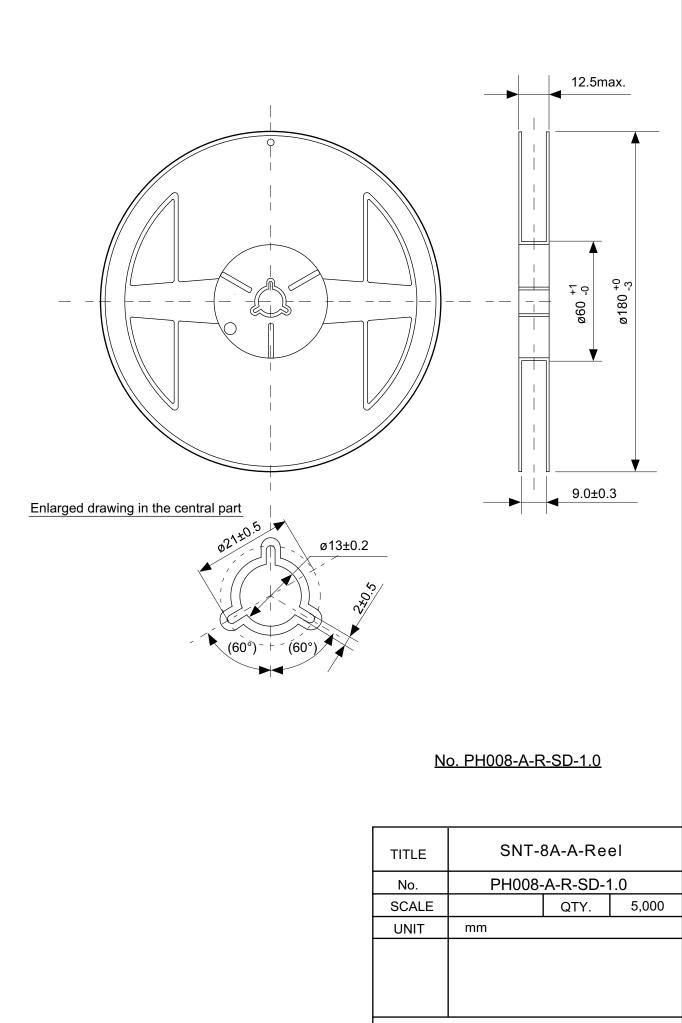


No. PH008-A-P-SD-2.0

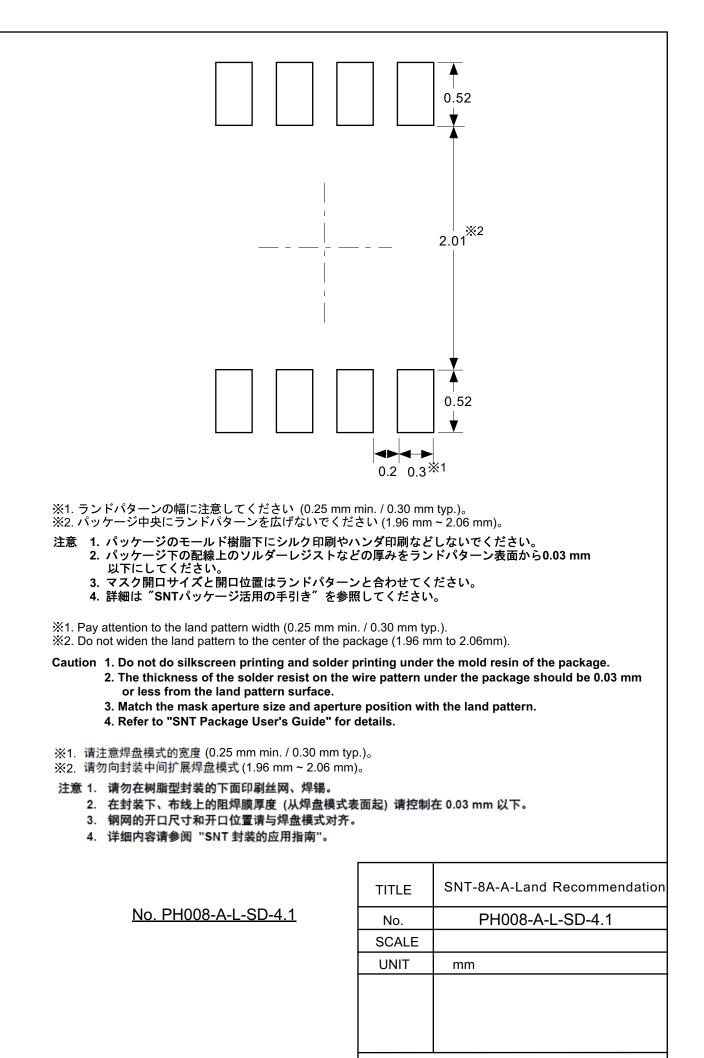
| TITLE                  | SNT-8A-A-PKG Dimensions |  |  |
|------------------------|-------------------------|--|--|
| No.                    | PH008-A-P-SD-2.0        |  |  |
| SCALE                  |                         |  |  |
| UNIT                   | mm                      |  |  |
|                        |                         |  |  |
|                        |                         |  |  |
|                        |                         |  |  |
|                        |                         |  |  |
| Seiko Instruments Inc. |                         |  |  |



| SNT-8A-A-Carrier Tape  |  |  |
|------------------------|--|--|
| PH008-A-C-SD-1.0       |  |  |
|                        |  |  |
| mm                     |  |  |
|                        |  |  |
|                        |  |  |
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| Seiko Instruments Inc. |  |  |
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Seiko Instruments Inc.



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|-------|-------------|-----|
|-------|-------------|-----|



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